

## General Description

The SY20763 is a three-cell synchronous boost Li-Ion battery charger designed for a 3.6-12.8V input voltage range, delivering a charge current of up to 1A. The charge current can be adjusted using an external resistor, offering flexibility for various portable applications.

The SY20763 uses a 500kHz switching frequency and includes full protection functions, including short-circuit, charge timeout, and temperature protection for reliable operation.

The charger features programmable charge timeout and adaptive input power limit functions, enhancing the safety of battery charging operations. The device includes 18V rated power switching and reverse blocking MOSFETs with extremely low ON resistance, ensuring high charge efficiency and simple peripheral circuit design.

The SY20763 is available in a compact QFN3x3 package.

## Features

- Adaptive Input Power Limit for 3.6-12.8V Range
- Integrated Synchronous Boost with 18V Rating Low R<sub>DS(ON)</sub> MOSFETs for High Efficiency
- Maximum 1A Constant Charge Current
- Constant Current / Constant Voltage / Trickle Current Charging Modes
- Programmable Charge Timeout
- Programmable Constant Charge Current
- Selectable Constant Voltage
- ±0.5% Battery Voltage Accuracy
- Thermal Regulation Protection
- Input Voltage UVLO and OVP
- Overtemperature Protection
- Output Short-Circuit Protection
- Normal Synchronous Boost Operation when the Battery is Removed
- Low Profile QFN3x3-16 Package for Portable Applications

## Applications

- Mobile Phones and Tablets
- Digital Cameras
- Battery Operated IoT devices
- Game Players
- Notebooks

## Typical Application

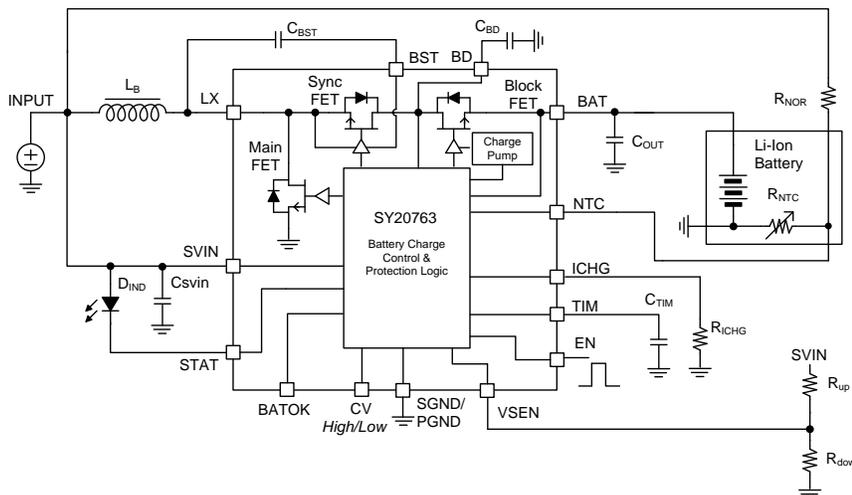


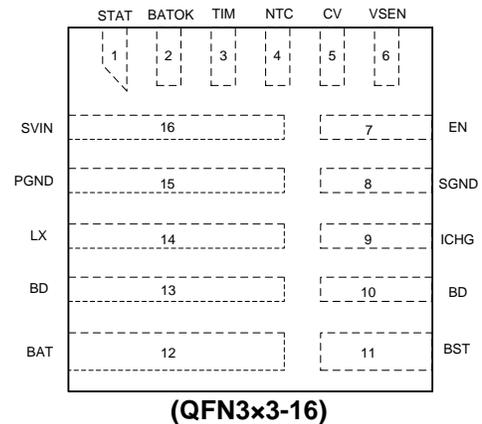
Figure 1. Schematic Diagram

## Ordering Information

SY20763 □(□□)□  
 └─ Temperature Code  
 └─ Package Code  
 └─ Optional Spec Code

| Ordering Number | Package Type | Top Mark |
|-----------------|--------------|----------|
| SY20763QDC      | QFN3x3-16    | BQWxyz   |

Device code: **BQW**  
*x=year code, y=week code, z= lot number code*



## Pinout (Top View)

| Pin Name | Pin Number | Pin Description  |
|----------|------------|--|
| STAT     | 1          | Charge status indication pin. Open drain output. Pull high to SVIN through a LED to indicate that charging is in progress. When charging is complete, the LED turns off.   |
| BATOK    | 2          | Good battery presence indication pin. When $V_{BAT}$ is lower than 9.1V, or NTC is pulled up to SVIN, the BATOK pin outputs a low logic level. Otherwise, the BATOK pin is in a high logic state.  |
| TIM      | 3          | Charge time limit pin. Connect this pin with a capacitor to the ground. The internal current source charges TC and CC mode capacitors to program the charging time limit. TC charge time limit is about 1/9 of the CC charge time limit.   |
| NTC      | 4          | Thermal protection pin. The UTP threshold is typically 76% of $V_{SVIN}$ , and the OTP threshold is typically 46.5% of $V_{SVIN}$ . Pulling up to SVIN can disable charging and make the device operate as a normal boost regulator. Pulling down to the ground shuts down the device.   |
| CV       | 5          | Battery CV voltage selection pin. Connect to GND for 12.6V charge termination voltage. Pull high for 13.05V charge termination voltage.  |
| VSEN     | 6          | Voltage sense pin for SVIN. If the voltage drops below the internal 1.195V reference voltage, $t_{SVIN}$ will be clamped to the setting value, and the input current will be limited.  |
| EN       | 7          | Enable control pin. Drive to logic high to enable operation and low logic to disable.  |
| SGND     | 8          | Signal ground pin.   |
| ICHG     | 9          | Charge current programming pin. Connect to GND with a resistor $R_{ICHG}$ . The mirror current of about 1/10000 of the blocking MOSFET current is converted to a voltage using the external RC network and compared to the internal reference 1V.<br>$I_{CC}=(1V/R_{ICHG})\times 10k$ , $I_{TC}=(1V/R_{ICHG})\times 1k+0.03$ . |
| BD       | 10, 13     | Connected to the drain of internal blocking MOSFET. Bypass with at least a 4.7 $\mu$ F ceramic cap to GND.   |
| BST      | 11         | MOSFET gate driver. Connect to the LX pin using a 0.1 $\mu$ F ceramic capacitor  |
| BAT      | 12         | Battery positive pin.  |
| LX       | 14         | Switch node pin. Connect it to the external inductor.  |
| PGND     | 15         | Power ground pin.  |
| SVIN     | 16         | Analog power input pin. Connect a MLCC from this pin to the ground to decouple high frequency noise..  |

**Absolute Maximum Ratings** (Note1)

|   |       |                |
|---|-------|----------------|
| STAT, NTC, CV, VSEN, EN, ICHG, BD, BAT, LX, SVIN                  | ----- | 18V            |
| BATOK, TIM, BST-LX  | ----- | 4V             |
| LX Pin Current Continuous   | ----- | 5A             |
| Power Dissipation, P <sub>D</sub> @ T <sub>A</sub> = 25°C, QFN3x3 | ----- | 2.6W           |
| Package Thermal Resistance (Note2)                                |       |                |
| θ <sub>JA</sub>   | ----- | 38°C/W         |
| θ <sub>JC</sub>   | ----- | 4°C/W          |
| Junction Temperature Range  | ----- | -40°C to 125°C |
| Lead Temperature (Soldering, 10 sec.)                             | ----- | 260°C          |
| Storage Temperature Range   | ----- | -65°C to 125°C |

**Recommended Operating Conditions** (Note3)

|   |       |                |
|---|-------|----------------|
| SVIN  | ----- | 3.6V to 12.8V  |
| STAT, NTC, CV, VSEN, EN, ICHG, BD, BAT, LX, | ----- | -0.3V to 16V   |
| BATOK, TIM, BST-LX                          | ----- | -0.3V to 3.3V  |
| LX Pin Current Continuous                   | ----- | 5A             |
| Junction Temperature Range                  | ----- | -40°C to 125°C |
| Ambient Temperature Range                   | ----- | -40°C to 85°C  |

## Electrical Characteristics

( $T_A=25^{\circ}\text{C}$ ,  $V_{IN}=5\text{V}$ ,  $\text{GND}=0\text{V}$ ,  $C_{IN}=4.7\mu\text{F}$ ,  $L=2.2\mu\text{H}$ ,  $R_{CHG}=10\text{k}\Omega$ ,  $C_{TIM}=470\text{nF}$ , unless otherwise specified.)

| Parameter   | Symbol            | Test Conditions                                       | Min    | Typ   | Max    | Unit          |
|---|-------------------|---|--------|-------|--------|---------------|
| <b>Bias Supply (<math>V_{SVIN}</math>)</b>            |                   |   |        |       |        |               |
| Supply Voltage  | $V_{SVIN}$        |   | 3.6    |       | 16     | V             |
| $V_{SVIN}$ Under Voltage Lockout Threshold            | $V_{UVLO}$        | $V_{SVIN}$ rising and measured from $V_{SVIN}$ to GND |        |       | 3.5    | V             |
| $V_{SVIN}$ Under Voltage Lockout Hysteresis           | $\Delta V_{UVLO}$ | Measured from $V_{SVIN}$ to GND                       |        | 100   |        | mV            |
| Input Overvoltage Protection                          | $V_{OVP}$         | $V_{SVIN}$ rising and measured from $V_{SVIN}$ to GND | 12.9   |       |        | V             |
| Input Overvoltage Protection Hysteresis               | $\Delta V_{OVP}$  | Measured from $V_{SVIN}$ to GND                       |        | 0.45  |        | V             |
| <b>Quiescent Current</b>                              |                   |   |        |       |        |               |
| Battery Discharge Current                             | $I_{BAT}$         | Shutdown IC, $\text{EN}=\text{NTC}=0$                 |        |       | 10     | $\mu\text{A}$ |
| Input Quiescent Current                               | $I_{IN}$          | Disable Charge, $\text{EN}=1, \text{NTC}=0$           |        |       | 1      | mA            |
| <b>Oscillator and PWM</b>                             |                   |   |        |       |        |               |
| Switching Frequency                                   | $f_{SW}$          |   |        | 500   |        | kHz           |
| Main N-FET Minimum OFF Time                           | $t_{MIN\_OFF}$    | With 18V rating                                       |        | 100   |        | ns            |
| Main N-FET Maximum OFF Time                           | $t_{MAX\_OFF}$    | With 18V rating                                       |        | 30    |        | $\mu\text{s}$ |
| Main N-FET Minimum ON Time                            | $t_{MIN\_ON}$     | With 18V rating                                       |        | 100   |        | ns            |
| <b>Power MOSFET</b>                                   |                   |   |        |       |        |               |
| $R_{DS(ON)}$ of Main N-FET                            | $R_{NFET\_M}$     |   |        | 80    |        | m $\Omega$    |
| $R_{DS(ON)}$ of Rectified N-FET                       | $R_{NFET\_R}$     |   |        | 40    |        | m $\Omega$    |
| $R_{DS(ON)}$ of Blocking N-FET                        | $R_{NFET\_B}$     |   |        | 40    |        | m $\Omega$    |
| <b>Voltage Regulation</b>                             |                   |   |        |       |        |               |
| Battery Charge Voltage                                | $V_{BAT\_REG}$    | $V_{CV}<1\text{V}$                                    | 12.537 | 12.6  | 12.663 | V             |
|   |                   | $V_{CV}>2\text{V}$                                    | 12.985 | 13.05 | 13.115 |               |
| High Level Logic for CV                               | $V_{CV\_H}$       |   | 2      |       |        | V             |
| Low Level Logic for CV                                | $V_{CV\_L}$       |   |        |       | 1      | V             |
| Recharge Threshold Refer to $V_{BAT\_REG}$            | $\Delta V_{RCH}$  |   | 150    | 300   | 450    | mV            |
| Trickle Current Charge Mode Battery Voltage Threshold | $V_{TRK}$         |   | 8.1    | 8.4   |        | V             |

| <b>Battery Connect Detection</b>                                       |                    |   |       |       |       |                |
|--|--------------------|---|-------|-------|-------|----------------|
| NTC Voltage Threshold for Battery Detect                               | $V_{DET}$          | NTC falling edge  | 85%   |       | 95%   | $V_{SVIN}$     |
| Detect Delay Time  | $t_{DET}$          |   |       | 30    |       | ms             |
| <b>Charge Current</b>  |                    |   |       |       |       |                |
| Internal Charge Current Accuracy for Constant Current Mode             |                    | $I_{CC}=1000mA$   | -10%  |       | 10%   |                |
| Internal Charge Current Accuracy for Trickle Current Mode              |                    | $I_{TC}=130mA$  | -50%  |       | 50%   |                |
| Termination Current  | $I_{TERM}$         | $I_{CC}=1000mA$   | 50    | 100   | 150   | mA             |
| <b>Output Voltage OVP</b>  |                    |   |       |       |       |                |
| Output Voltage OVP Threshold   | $V_{OVP}$          |   | 105%  | 110%  | 115%  | $V_{BAT\_REG}$ |
| <b>Input Voltage Threshold for Adaptive Current Limit</b>              |                    |   |       |       |       |                |
| Voltage Reference of $V_{SEN}$   | $V_{SEN}$          | $V_{SVIN} \leq 6V$  | 1.171 | 1.195 | 1.219 | V              |
| The Adaptive Input Power Limit Reference is $V_{SVIN}-\Delta V_{AICL}$ | $\Delta V_{AICL}$  | $V_{SVIN} > 6V$   |       | 0.53  |       | V              |
| <b>Timer</b>   |                    |   |       |       |       |                |
| Trickle Current Charge Timeout   | $t_{TC}$           | $C_{TIM}=330nF$   | 0.4   | 0.5   | 0.65  | hour           |
| Constant Current Charge Timeout  | $t_{CC}$           |   | 3.8   | 4.5   | 5.82  | hour           |
| Charge Mode Change Delay Time  | $t_{MC}$           |   |       | 30    |       | ms             |
| Termination Delay Time   | $t_{TERM}$         |   |       | 30    |       | ms             |
| Recharge Time Delay  | $t_{RCHG}$         |   |       | 30    |       | ms             |
| <b>Short Circuit Protection</b>  |                    |   |       |       |       |                |
| Output Short Protection Threshold is $V_{SVIN}-\Delta V_{SHORT}$       | $\Delta V_{SHORT}$ |   |       | 2.3   |       | V              |
| <b>BATOK Indication</b>  |                    |   |       |       |       |                |
| BATOK High Voltage Output  | $V_{BATOK\_H}$     |   |       | 3     |       | V              |
| BATOK Low Voltage Output   | $V_{BATOK\_L}$     |   |       | 0     |       | V              |
| <b>Linear Charger Mode</b>   |                    |   |       |       |       |                |
| Battery Charger Current when the Blocking FET is in Linear Mode        | $I_{SC}$           | $V_{BAT} < V_{SVIN} - \Delta V_{SHORT}$<br>when $I_{CC}=1000mA$ |       | 130   |       | mA             |
| BD Voltage Regulation  | $V_{BD}$           |   |       | 9.24  |       | V              |
| <b>Enable ON/OFF Control</b>   |                    |   |       |       |       |                |
| High Level Logic for Enable Control                                    | $V_{EN\_H}$        |   | 1.5   |       |       | V              |
| Low Level Logic for Enable Control                                     | $V_{EN\_L}$        |   |       |       | 0.4   | V              |

| Battery Thermal Protection NTC          |                     |              |       |       |       |                   |
|---|---------------------|--------------|-------|-------|-------|-------------------|
| Under Temperature Protection            | $V_{NTC\_UTP}$      |              | 75%   | 76%   | 77%   | V <sub>SVIN</sub> |
| Under Temperature Protection Hysteresis | $V_{NTC\_UTP\_HYS}$ | Falling edge |       | 6%    |       |                   |
| Over Temperature Protection             | $V_{NTC\_OTP}$      |              | 45.5% | 46.5% | 47.5% |                   |
| Over Temperature Protection Hysteresis  | $V_{NTC\_OTP\_HYS}$ | Rising edge  |       | 2%    |       |                   |
| Thermal Fold-back and Thermal Shutdown  |                     |              |       |       |       |                   |
| Thermal Fold-back Threshold             | $T_{Fold}$          | Rising edge  |       | 120   |       | °C                |
| Thermal Fold-back Threshold Hysteresis  | $T_{Fold\_HYS}$     |              |       | 20    |       | °C                |
| Thermal Fold-back Ratio                 |                     |              |       | 0.25  |       | I <sub>CC</sub>   |
| Thermal Shutdown Temperature            | $T_{SD}$            | Rising edge  |       | 160   |       | °C                |
| Thermal Shutdown Temperature Hysteresis | $T_{SD\_HYS}$       |              |       | 30    |       | °C                |

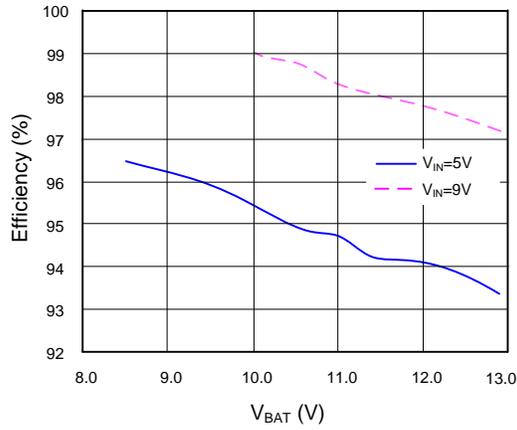
**Note 1:** Stresses beyond the “Absolute Maximum Ratings” may cause permanent damage to the device. These are stress ratings only. Functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

**Note 2:**  $\theta_{JA}$  is measured in the natural convection at  $T_A = 25^\circ\text{C}$  on a low effective four-layer thermal conductivity test board of JEDEC 51-3 thermal measurement standard.

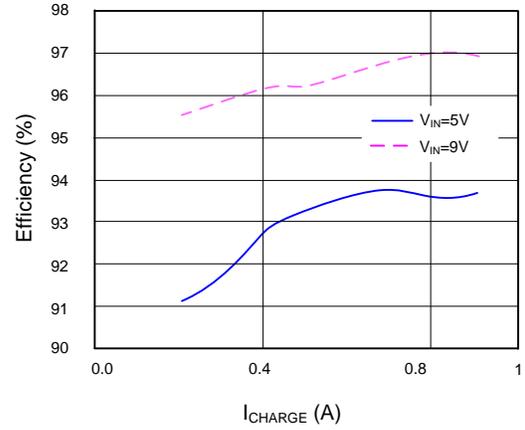
**Note 3:** The device is not guaranteed to function outside its operating conditions

## Typical Performance Characteristics

Efficiency VS BAT Voltage ( CC mode )

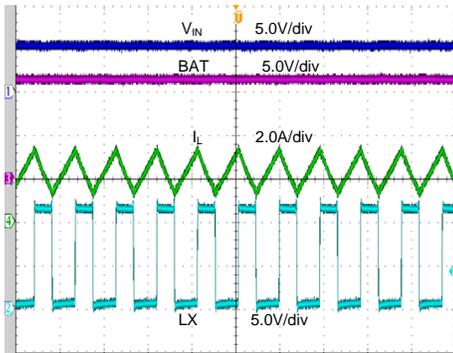


Efficiency VS Charge Current( CV mode )



Steady Waveforms (CC Mode)

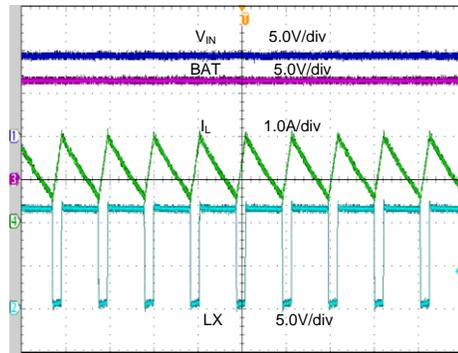
(V<sub>IN</sub>=5.0V, V<sub>BAT</sub>=11V)



Time (2.0us/div)

Steady Waveforms (CC Mode)

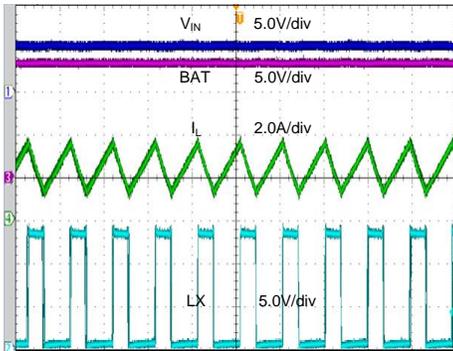
(V<sub>IN</sub>=9.0V, V<sub>BAT</sub>=11V)



Time (2.0us/div)

Steady Waveforms (CV Mode)

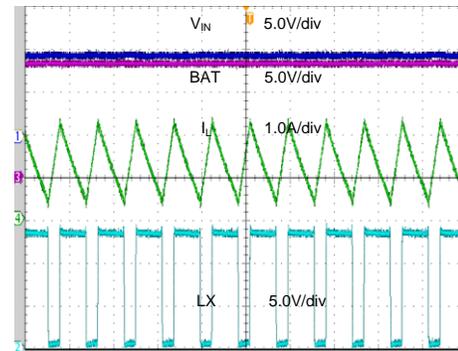
(V<sub>IN</sub>=5.0V, I<sub>CC</sub>=0.9A)



Time (2.0us/div)

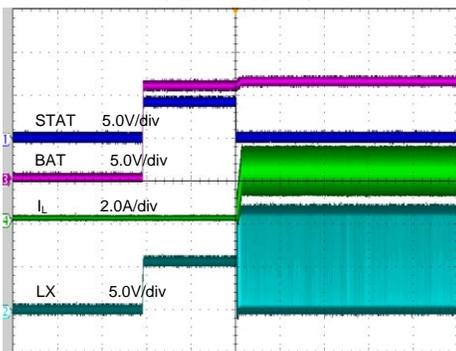
Steady Waveforms (CV Mode)

(V<sub>IN</sub>=9.0V, I<sub>CC</sub>=0.9A)



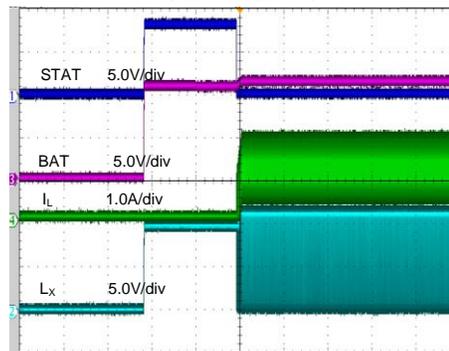
Time (2.0us/div)

Power ON (CC Mode)  
( $V_{IN}=5.0V$ ,  $V_{BAT}=11V$ )



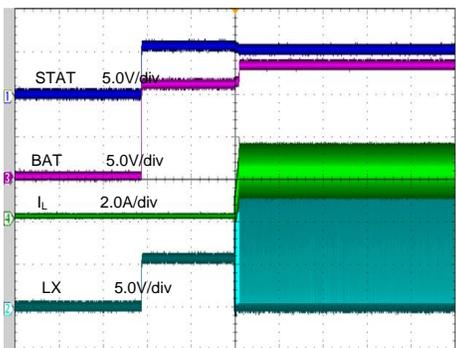
Time (400ms/div)

Power ON (CC Mode)  
( $V_{IN}=9.0V$ ,  $V_{BAT}=11V$ )



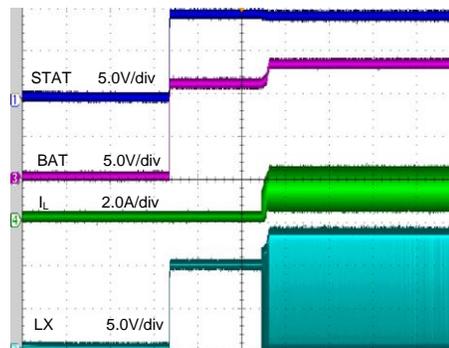
Time (400ms/div)

Power ON (CV Mode)  
( $V_{IN}=5.0V$ ,  $I_{CC}=0.9A$ )



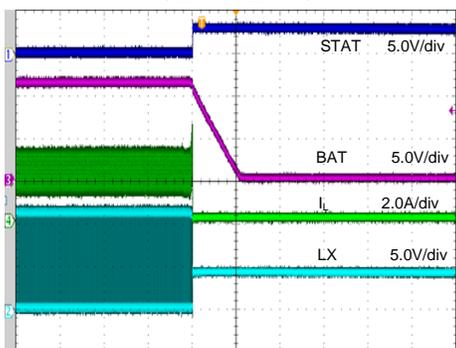
Time (400ms/div)

Power ON (CV Mode)  
( $V_{IN}=9.0V$ ,  $I_{CC}=0.9A$ )



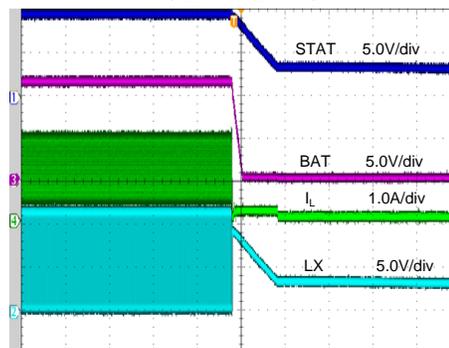
Time (400ms/div)

Power OFF (CC Mode)  
( $V_{IN}=5.0V$ ,  $V_{BAT}=11V$ )



Time (2ms/div)

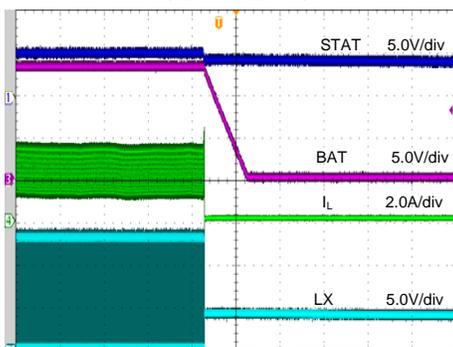
Power OFF (CC Mode)  
( $V_{IN}=9.0V$ ,  $V_{BAT}=11V$ )



Time (10ms/div)

Power OFF (CV Mode)

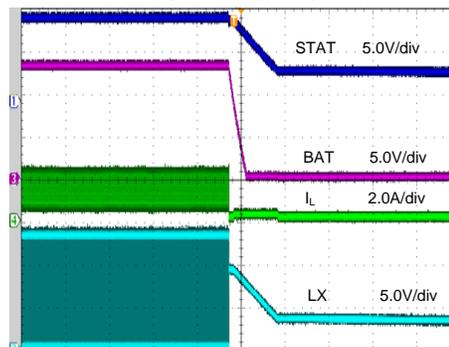
( $V_{IN}=5.0V$ ,  $I_{CC}=0.9A$ )



Time (4ms/div)

Power OFF (CV Mode)

( $V_{IN}=9.0V$ ,  $V_{BAT}=11V$ )



Time (10ms/div)

## Application Information

The SY20763 is a three-cell synchronous boost Li-Ion battery charger designed for 3.6-12.8V input voltage range, delivering a charge current of up to 1A. The charge current can be adjusted using an external resistor, offering flexibility for various portable applications.

The SY20763 uses 500kHz switching frequency and integrates protection functions, including short-circuit, charge timeout, and temperature protection for reliable operation.

The charger features programmable charging timeout and adaptive input power limit functions, enhancing the safety of battery charging operations. The device includes 18V rated power switching and reverse blocking MOSFETs with extremely low ON resistance, ensuring high charging efficiency and simple circuit design for USB input applications. The device can operate and provide power to the system with or without a Li-Ion battery connected.

### Charging Status Indication Description:

1. **Charge-in-Process:**
  - a) STAT pin is pulled low.
2. **Charge Done:**
  - a) STAT pin is high impedance.
3. **Fault Mode:**
  - a) In Fault Mode, the LED alternates between high and low voltage at a frequency of 1.3Hz.

Connect an LED from SVIN to the STAT pin.

- LED on indicates charging-in-process.
- LED off indicates charging is done.
- LED flashing at 1.3Hz indicates fault mode.

## Switching Mode Boost Charger Operation

### Switching Mode Control:

The SY20763 is a fixed switching frequency boost charger for USB power input applications. The frequency is fixed at 500kHz, allowing for minimized peripheral circuit design for size optimization.

### Operation:

The SY20763 can operate with or without a Li-Ion battery.

### Battery Present:

When the battery is present, the SY20763 will adapt to various charging modes based on battery state, including constant current charge mode, constant voltage charge mode, and trickle charge mode.

### Battery Absent:

If no battery connection is detected through the NTC pin, SY20763 will operate as a normal switching mode boost converter. The internal constant current loop and voltage loop are both active.

### Protections Features:

The SY20763 includes battery charging protection features. When the input or output overvoltage protection, thermal protection, or timeout protection are triggered, the boost charger stops switching immediately. The short circuit protection is triggered when V<sub>BAT</sub> is lower than V<sub>SVIN</sub> - ΔV<sub>SHORT</sub>. The main MOSFET will be turned off immediately. The blocking MOSFET will enter linear mode with 1/10 I<sub>CC</sub>+0.03 charging current. When V<sub>BAT</sub> rises higher than V<sub>SVIN</sub> - ΔV<sub>SHORT</sub>, the boost charger will restart operation at light load and regulate V<sub>BD</sub> to 9.24V (typ.). A linear charging current is used, with a value of 1/10 I<sub>CC</sub>+0.03. When V<sub>BAT</sub> goes above V<sub>TRK</sub>, the boost switching charger takes over.

### Adaptive Input Current Limit:

The SY20763 can limit the input power on the fly, and adjust this threshold according to the input voltage. It automatically decreases the charge current when V<sub>SVIN</sub> voltage drops to the adaptive input power limit reference V<sub>ref</sub>.

For a typical 5V adapter, V<sub>ref</sub> is set by the V<sub>SEN</sub> pin. The V<sub>ref</sub> is calculated using the equation:

$$V_{ref} = 1.195 \times \frac{R_{UP} + R_{DN}}{R_{DN}}$$

If V<sub>SVIN</sub> voltage is higher than 6V, V<sub>ref</sub> is calculated using the equation:

$$V_{ref} = V_{SVIN} - \Delta V_{AICL}$$

Where: ΔV<sub>AICL</sub> is 0.53V, and V<sub>SVIN</sub> is the input voltage when the adapter is inserted.

### Constant Voltage Threshold Programming:

The SY20763 can program the constant voltage threshold using the CV pin. When V<sub>CV</sub> is higher than 2V, the constant voltage threshold is set to 13.05V; when V<sub>CV</sub> is lower than 1V, the constant voltage threshold is set to 12.6V.

## Design Procedure

The following paragraphs provide information on the selection process for the input capacitor ( $C_{IN}$ ), output capacitor ( $C_{OUT}$ ), inductor (L), NTC resistors ( $R_1$  and  $R_2$ ), input voltage threshold resistors ( $R_{up}$  and  $R_{down}$ ), and timer capacitor ( $C_{TIM}$ ) based on the target application specifications.

### NTC Resistor:

The SY20763 monitors battery temperature by measuring the input voltage and NTC voltage. The controller triggers the UTP or OTP when K ( $K = V_{NTC}/V_{SVIN}$ ) reaches the threshold for UTP ( $K_{UT}$ ) or OTP ( $K_{OT}$ ). The temperature sensing network is shown below:

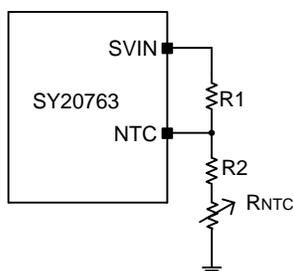


Figure 2. UTP /OTP configuration using R1 and R2

The calculation steps are:

1. Define  $K_{UT}$ ,  $K_{UT} = 75\sim 77\%$
2. Define  $K_{OT}$ ,  $K_{OT} = 45.5\sim 47.5\%$
3. Assume the resistance of the battery NTC thermistor is  $R_{UT}$  at the UTP threshold and  $R_{OT}$  at the OTP threshold.
4. Calculate R2:

$$R_2 = \frac{K_{OT}(1-K_{UT})R_{UT} - K_{UT}(1-K_{OT})R_{OT}}{K_{UT} - K_{OT}}$$

5. Calculate R1:

$$R_1 = (1/K_{OT} - 1)(R_2 + R_{OT})$$

When typical values ( $K_{UT} = 76\%$  and  $K_{OT} = 46.5\%$ ) are used, substituting the equations become :

$$R_2 = 0.378R_{UT} - 1.378R_{OT}$$

$$R_1 = 1.151(R_2 + R_{OT})$$

### Timer Capacitor $C_{TIM}$ :

The charger provides a programmable safety charging timer. The charging time is programmed using a capacitor connected between the TIM and GND pins. The capacitance is calculated as follows:

$$C_{TIM} = 2 \times 10^{-11} S \times T_{CC}$$

Where:

- $T_{CC}$  is the target constant charge time, unit: s.
- Units are in F.

### Input Capacitor $C_{IN}$ :

The ripple current through the input capacitor can be estimated using the following equation:

$$I_{C_{IN\_RMS}} = \frac{V_{IN} \times (V_{OUT} - V_{IN})}{2\sqrt{3} \times L \times F_{SW} \times V_{OUT}}$$

To handle this ripple current, X5R or X7R ceramic capacitors with greater than  $4.7\mu F$  capacitance are recommended.

### Output Capacitor $C_{OUT}$ :

The output capacitor is selected to handle the output ripple requirements. The ripple voltage is related to the capacitance and its equivalent series resistance (ESR). Using X5R or a better grade low ESR ceramic capacitor is recommended for best performance. The voltage rating of the output capacitor should be higher than the maximum output voltage. The minimum required capacitance can be calculated with the following equation:

$$C_{OUT} = \frac{I_{CC} \times (V_{OUT} - V_{IN})}{F_{SW} \times V_{OUT} \times V_{RIPPLE}}$$

Where

- $V_{RIPPLE}$  is the peak to peak output ripple.
- $I_{CC}$  is the set charge current.

During normal operation, the output capacitor is in parallel with  $C_{BD}$ . A capacitance of more than  $10\mu F$  is recommended for  $C_{OUT}$  and  $C_{BD}$ .

### Inductor L:

When selecting the inductor, consider the following factors:

1. Choose the inductance to achieve the desired ripple current. It is suggested that the ripple current be approximately 40% of the average input current.
2. The inductance is calculated as follows:

$$L = \left( \frac{V_{IN}}{V_{OUT}} \right)^2 \frac{(V_{OUT} - V_{IN})}{I_{CC} \times F_{SW} \times 40\%}$$

Where:

- $F_{SW}$  is the switching frequency.
- $I_{CC}$  is the set charging current.

The SY20763 is tolerant to different ripple current amplitudes. Therefore, the final inductance selection can deviate slightly from the calculated value without significantly affecting performance.

3. The saturation current rating of the inductor must be selected to be greater than the peak inductor current under full load conditions.

$$I_{SAT,MIN} > \left( \frac{V_{OUT}}{V_{IN}} \right) \times I_{CC} + \left( \frac{V_{IN}}{V_{OUT}} \right)^2 \frac{(V_{OUT} - V_{IN})}{2 \times F_{SW} \times L}$$

- The DC resistance (DCR) of the inductor and the core loss at the switching frequency should be sufficiently low to meet the desired efficiency requirements. It is recommended to select an inductor with DCR < 10mΩ.

- To minimize noise and improve efficiency, place the following components close to the IC: C<sub>SVIN</sub>, L, C<sub>BD</sub>.
- The loop of the main MOSFET, rectifier diode, and C<sub>BD</sub> must be minimized.
- Place C<sub>SVIN</sub> close to the SVIN and GND pins.
- Minimize the PCB copper area associated with the LX pin to reduce EMI.
- Place the small signal components (R<sub>ICHG</sub>, R<sub>up</sub>, and R<sub>down</sub>) close to the device but not adjacent to the LX net on the PCB layout to avoid crosstalk.

### PCB Layout Guide:

For best performance of the SY20763, the following guidelines must be followed:

- Enhance thermal dissipation and reduce noise by maximizing the PCB copper area connected to the GND pin.

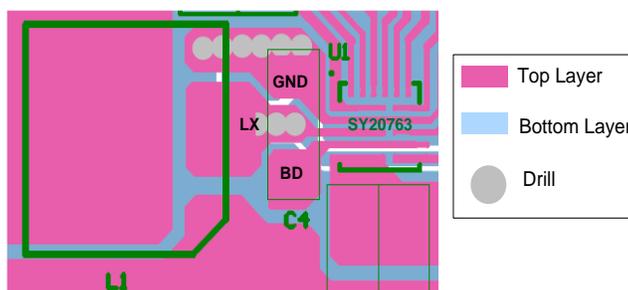
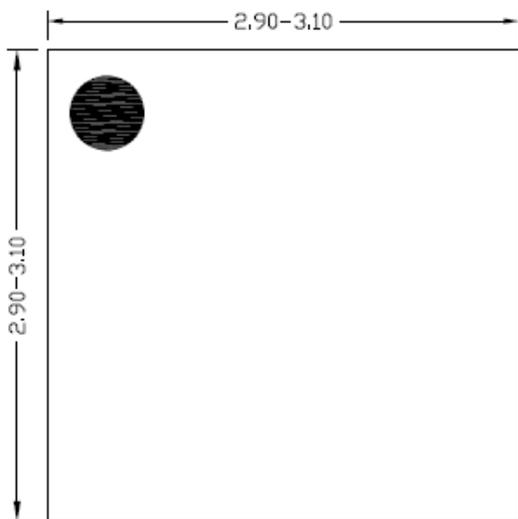
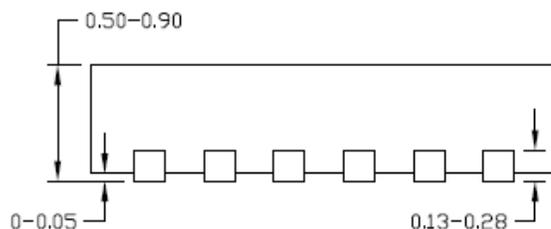


Figure 3. PCB Layout Suggestion

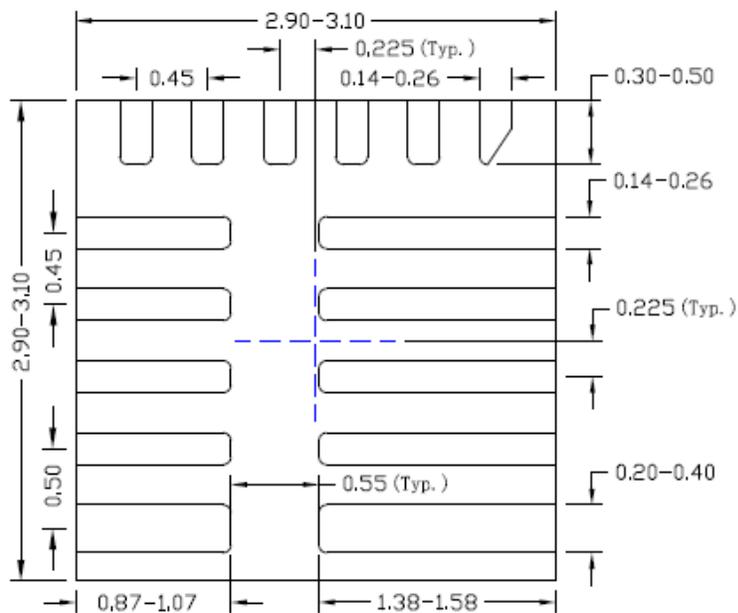
**QFN3x3-16 Package Outline Drawing**



**Top View**



**Side View**

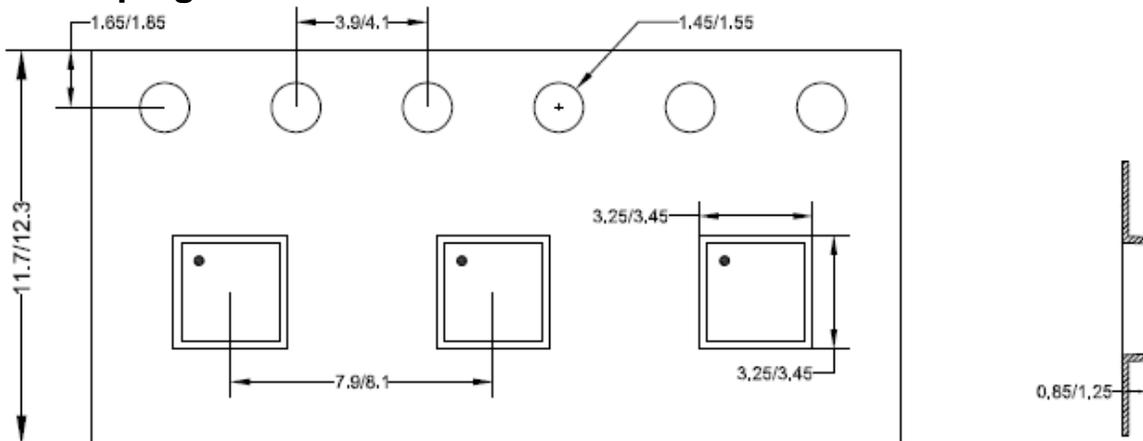


**Bottom View**

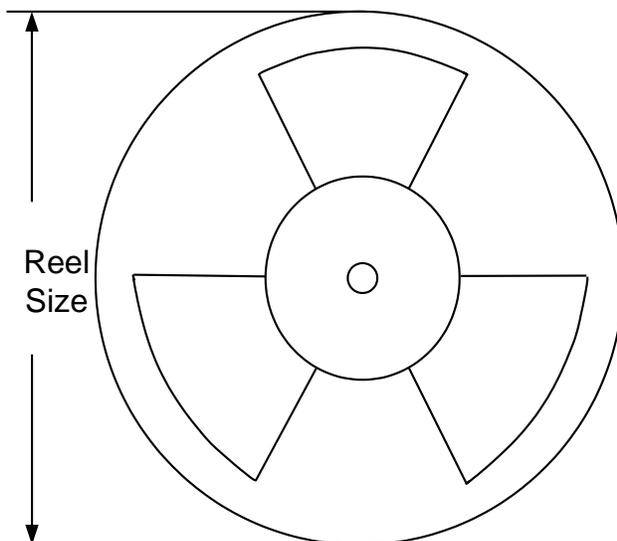
*Note: All dimensions are in millimeters and exclude mold flash and metal burr.*

## Taping & Reel Specification

### 1. QFN3x3 Taping Orientation



### 2. Carrier Tape & Reel Specification for Packages



| Package types | Tape width (mm) | Pocket pitch (mm) | Reel size (Inch) | Trailer length (mm) | Leader length (mm) | Qty per reel |
|---------------|-----------------|-------------------|------------------|---------------------|--------------------|--------------|
| QFN3x3        | 12              | 8                 | 13"              | 400                 | 400                | 5000         |



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